

TLE4990

TLE4990-E6782

Programmable Linear Output Hall Sensor



Sensors



Never stop thinking

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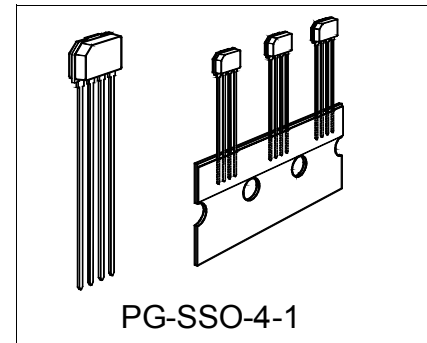


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## 1 Overview

### 1.1 Features

- Single supply voltage 4.5 - 5.5 V
- Temperature Range from -40 °C up to 150 °C
- Very slim 4-pin package with only 1mm thickness
- Temperature compensation
- Programmable parameters stored in fuse memory:
  - magnetic range and magnetic sensitivity (gain)
  - zero field voltage (offset)
  - clamping option
  - memory lock
  - temperature coefficient (calibrated and fused during production)
- Low drift of output signal over temperature and lifetime
- Continuous measurement ranges between -200 mT and +200 mT or 0 and 400 mT
- Output short circuit protection
- Very linear and ratiometric rail-to-rail output signal with push-pull output
- Reverse polarity and overvoltage protection for all pins
- On-board diagnostics (wire breakage detection)
- Individual programming and operation of multiple sensors with common power supply
- Completely calibrated and fused version -E6782



### 1.2 Target Applications

- Robust replacement of potentiometers
  - No mechanical abrasion
  - Resistant to humidity, temperature, pollution, and vibration
- Linear and angular position sensing in automotive applications like pedal position, suspension control, valve or throttle position, headlight levelling, and steering angle
- High current sensing for battery management, motor control, and electronic fuse

Type	Package
TLE4990	PG-SSO-4-1
TLE4990-E6782	PG-SSO-4-1

## 2 Functional Description

### Pin Configuration

Figure 1 shows the location of the hall element in the chip.

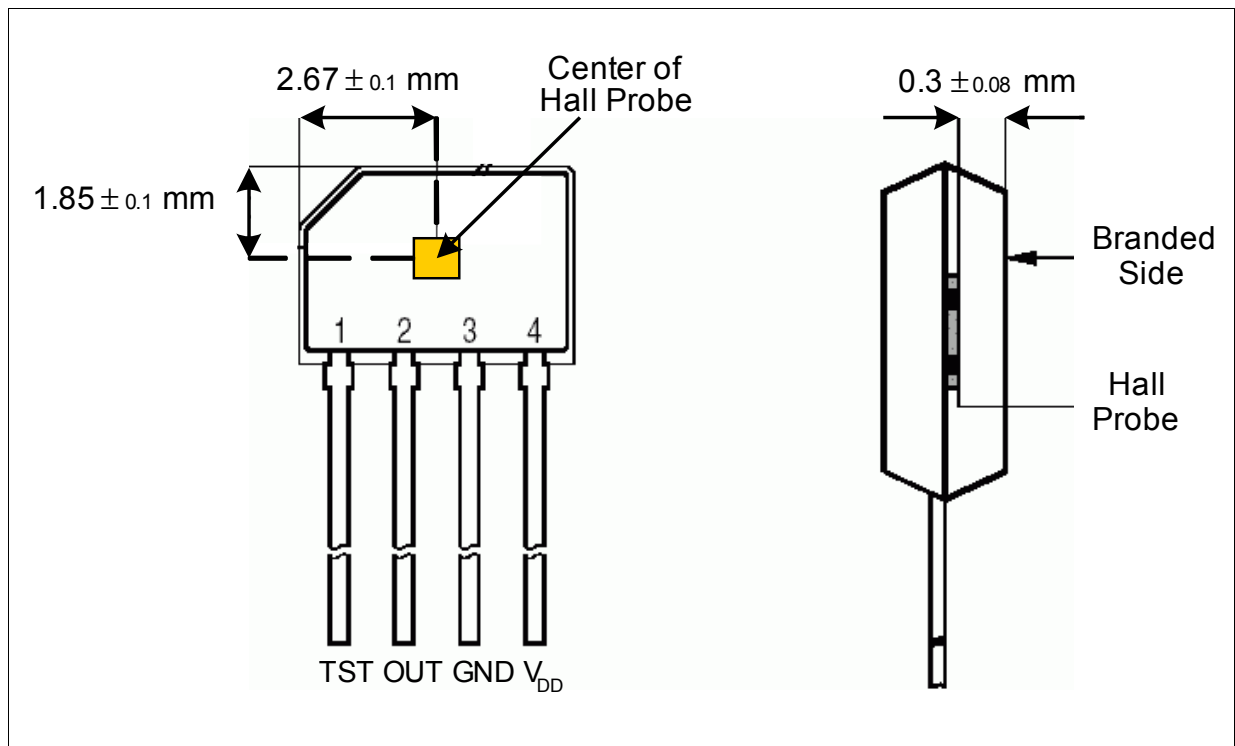


Figure 1 Pin Configuration and Hall Cell Location

Table 1 Pin Definitions and Functions

Pin No.	Symbol	Function
1	<i>TST</i>	Test pin, must be grounded
2	<i>OUT</i>	Output voltage / programming interface
3	<i>GND</i>	Ground
4	<i>V<sub>DD</sub></i>	Supply voltage / programming interface

**General**

The linear Hall IC TLE4990 has been designed specifically to meet the demands of highly accurate rotation and position detection, as well as for current measurement applications.

The sensor provides a ratiometric analog output voltage which is ideally suited for A/D conversion with the supply voltage as a reference.

The IC is produced in BiCMOS technology with high voltage capability and also providing reverse polarity protection.

**Zero-field Output Voltage ( $V_{zero}$ )**

The output voltage with no magnetic field present is called the zero field voltage  $V_{zero}$ . It is programmable within the range of 3% to 19% of  $V_{DD}$  (for Bipolar bit = 0) and 40% to 60% of  $V_{DD}$  (for Bipolar bit = 1) by 10 ODAC bits with a resolution of 1.0 mV to 1.2 mV.

**Magnetic Sensitivity (S)**

The magnetic sensitivity is set in two steps: First the “coarse gain” is selected out of 8 values (3 PRE bits). Then the “fine gain” is adjusted by another 10 GDAC bits.

The resulting range of sensitivity extends from 15 mV/mT to 180 mV/mT at the nominal supply voltage of 5 V. Note that as the sensitivity is ratiometric, it will also depend linearly on the supply voltage.

The sensitivity of the -E6782 version is programmed during production. It is calibrated to a value of 20 mV/mT at the nominal supply voltage of 5 V.

**Temperature Gain Compensation**

The temperature compensation of the sensitivity is programmed during production. The value of +350 ppm/°C provides an excellent accuracy for the use of a SmCo permanent magnet. Stability is achieved by the dynamic offset cancellation technique to eliminate any spurious mechanical or temperature effects.

**Clamping Option**

It is possible to reduce the output voltage swing from its original 3%... 97%  $V_{DD}$  to a limited swing of 10% ... 90%  $V_{DD}$  by setting the clamping bit. This allows to detect a broken wire. In this case the output voltage is tied to  $\leq 6\%$  or  $\geq 94\%$  of  $V_{DD}$ .

*Note: The -E6782 version has this feature disabled.*

## Block Diagram

Figure 2 shows a simplified block diagram.

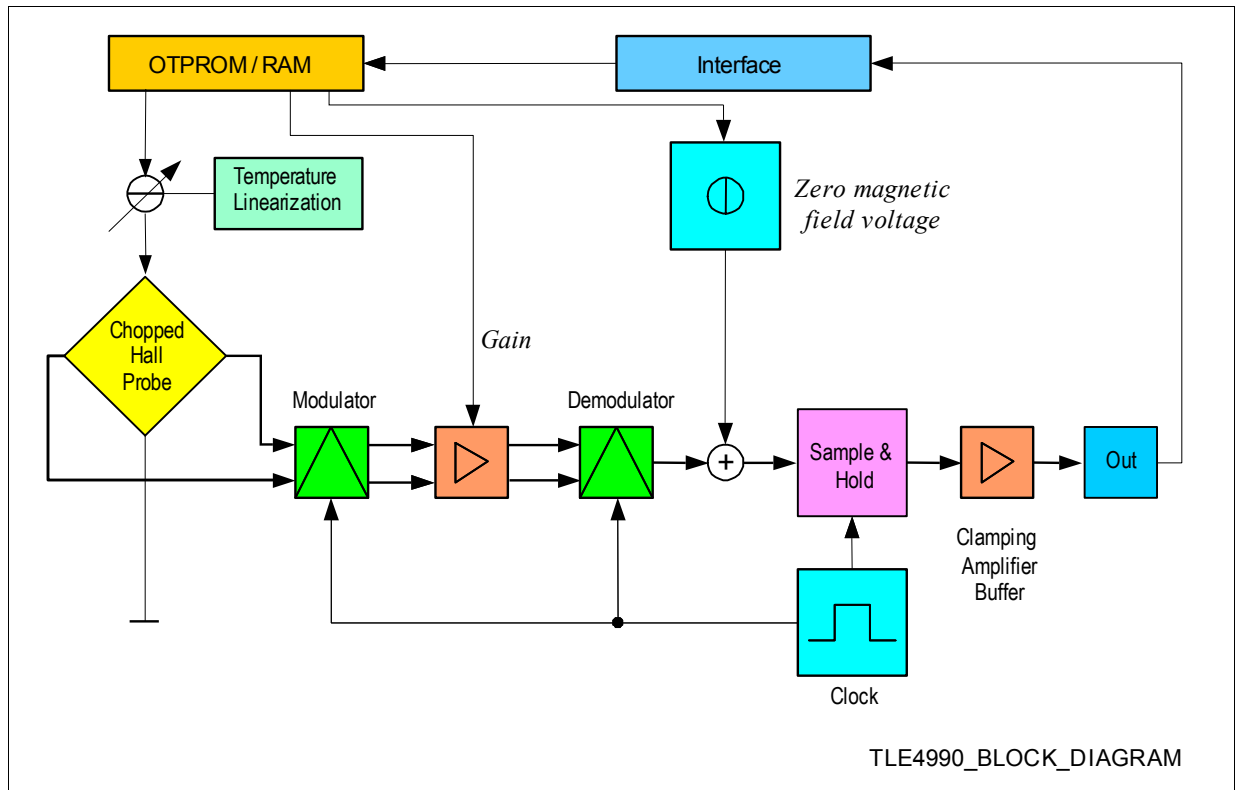


Figure 2 Block Diagram

## Principle of Operation

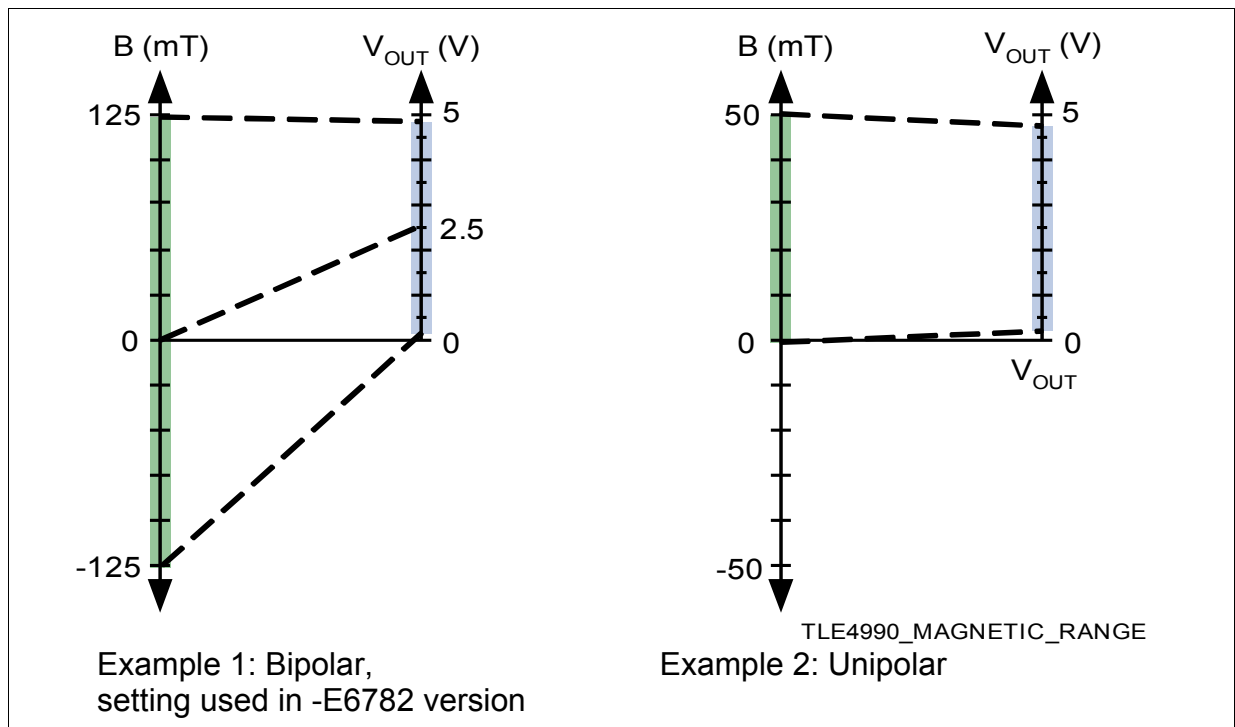
- A magnetic flux is measured by a Hall-Effect cell.
- The Temperature compensation modulates the bias current of the hall cell.
- The output signal from the Hall-Effect cell is amplified.
- A zero field voltage is added.
- The output voltage range can be clamped by limiters.
- The final output value is amplified and buffered.
- The output voltage is proportional to the supply voltage (ratiometric behavior).
- An OBD (**O**n **B**oard **D**iagnostics) circuit connects the output to  $V_{DD}$  or GND in case of errors.



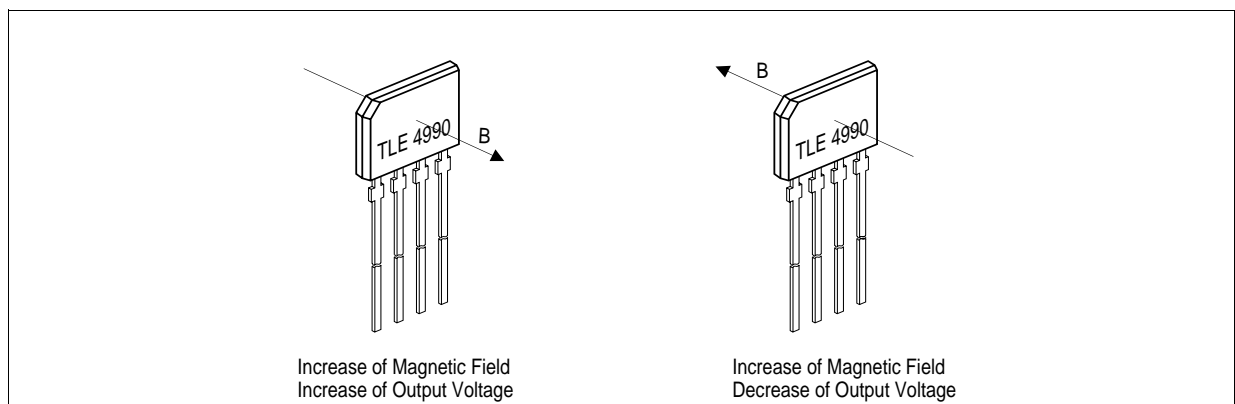
### Transfer Functions

The examples in **Figure 3** show how different magnetic field ranges can be mapped to the output voltage.

- Polarity mode:
  - **Unipolar**: only magnetic fields in one direction are measured. The zero field voltage is near to the GND level.
  - **Bipolar**: Magnetic fields can be measured in both orientations. The zero field voltage is about the half voltage.



**Figure 3** Examples of Operation



**Figure 4** Magnetic Field Direction Definition

### 3 Absolute Maximum Ratings

**Table 2 Absolute Maximum Rating Parameters <sup>1)</sup>**

Parameter	Symbol	Limit Values		Unit	Notes
		min.	max.		
Storage temperature	$T_{ST}$	-40	150	°C	
Junction temperature	$T_J$	-40	160	°C	
Voltage on $V_{DD}$ pins with respect to ground ( $V_{SS}$ )	$V_{DD}$	-18	24	V	for $T_A \leq 80$ °C max. 10 min.
Voltage on output pin with respect to ground ( $V_{SS}$ )	$V_{OUTov}$	-0.3	16		for $T_A \leq 80$ °C max. 5 min.
Magnetic field	$B_{MAX}$	-	unlimited	T	
ESD protection	$V_{ESD}$	-	2.0	kV	according HBM JESD22-A114-B

<sup>1)</sup> Only valid if the MEMlock bit is set and the TST pin is connected to GND.

*Note: Stresses above those listed under “Absolute Maximum Ratings” may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability. During absolute maximum rating overload conditions ( $V_{IN} > V_{DD}$  or  $V_{IN} < V_{SS}$ ) the voltage on  $V_{DD}$  pins with respect to ground ( $V_{SS}$ ) must not exceed the values defined by the absolute maximum ratings.*

## 4 Operating Range

The following operating conditions must not be exceeded in order to ensure correct operation of the TLE4990. All parameters specified in the following sections refer to these operating conditions, unless otherwise noticed.

**Table 3 Operating Condition Parameters<sup>1)</sup>**

Parameter	Symbol	Limit Values		Unit	Notes
		min.	max.		
Supply voltage	$V_{DD}$	4.5	5.5	V	
Load resistance	$R_L$	4.7 7	-	k $\Omega$	for OBD parameters <sup>2)</sup>
Load capacitance	$C_L$	0	50	nF	<sup>3)</sup>
Ambient temperature <sup>4)</sup>	$T_A$	-40	150	$^{\circ}\text{C}$	

<sup>1)</sup> Keeping signal levels within the limits specified in this table, ensures operation without overload conditions.

<sup>2)</sup> OBD= **O**n **B**oard **D**iagnostics (see [Table 12](#)).

<sup>3)</sup> A minimum capacitance of 1 nF is recommended in order to improve the EMC behavior.

<sup>4)</sup>  $R_{THja} \leq 150 \text{ K/W}$

## 5 Electrical and Magnetic Parameters

### Electrical Parameters

**Table 4 Electrical characteristics**

Parameter	Symbol	Limit Values			Unit	Notes
		min.	typ.	max.		
Output voltage range	$V_{OUT}$	3	-	97	% of $V_{DD}$	$R_{LOAD} \geq 4.7 \text{ k}\Omega$
Supply current	$I_{DD}$	3.5	-	5.5	mA	$I_{OUT} = 0 \text{ mA}$ <sup>1)</sup>
Output current	$I_{OUT}$	-1.2	-	1.2	mA	
Output Resistance	$R_{OUT}$	-	3	11.2	$\Omega$	<sup>1)</sup>
Zero field voltage	$V_{ZERO}$	3	-	18	% $V_{DD}$	Bipolar-Bit = 0 <sup>2) 3)</sup> Bipolar-Bit = 1 <sup>2) 3)</sup>
		42	-	59		
		49.95	50	50.05		only version -E6782 <sup>3)</sup>
Zero field voltage drift	$\Delta V_{ZERO}$	-10	-	10	mV	over lifetime
		-30	-	0		$-40^\circ\text{C} \leq T < 25^\circ\text{C}$
		-30	-	0		$25^\circ\text{C} \leq T \leq 150^\circ\text{C}$
		-40	-	0		$-40^\circ\text{C} \leq T \leq 150^\circ\text{C}$ <sup>4)</sup>
Ratiometry	$Rat$	99.8	100	100.2	%	<sup>5)</sup>
Power on time	$t_{Pon}$	0.3	0.6	0.75	ms	<sup>6)</sup>
Max. phase shift error	$\phi_{ERR}$	2	4	8	degree	@ 100 Hz sine input
Output noise	$V_{noise}$	-	1.2	-	mV <sub>RMS</sub>	<sup>7)</sup>
Maximum operating frequency	$f_{op}$	1.1	1.6	2.3	kHz	-3 dB corner frequency

<sup>1)</sup> Valid for  $V_{OUT}$  in the range from 10% to 90%  $V_{DD}$ .

<sup>2)</sup> Not for the -E6782 version.

<sup>3)</sup> @ 25 °C

<sup>4)</sup> For Sensitivity  $S < 80 \text{ mV/mT}$ , for higher sensitivities the zero field drift is dominant (see [Table 5](#)).

<sup>5)</sup> Definition:  $Rat = (V_{OUT}(V_{DD}) / V_{DD}) / (V_{OUT}(V_{DD} = 5 \text{ V}) / 5 \text{ V}) \times 100\%$   
for  $V_{out}$  in the range from 10%  $V_{DD}$  to 90%  $V_{DD}$ .

<sup>6)</sup> The output voltage has reached 99% of its final value within  $t_{Pon}$  after power on.

<sup>7)</sup> No external filtering, with a sensitivity of 30 mV/mT (digital switching noise included) @ 25 °C.

### Magnetic Parameters

**Table 5 Magnetic Characteristics**

Parameter	Symbol	Limit Values			Unit	Notes
		min.	typ	max.		
Sensitivity	$S$	15	-	180	mV/mT	programmable for TLE4990 <sup>1) 2)</sup>
		19.8	20	20.2	mV/mT	TLE4990-E6782 <sup>1) 3)</sup>
Magnetic field range	$MFR$	$\pm 13.05$	-	$\pm 204.5$	mT	Bipolar-Bit = 1 <sup>4)</sup>
		26.1	-	409		Bipolar-Bit = 0 <sup>4)</sup>
		$\pm 115.8$	$\pm 117.5$	$\pm 118.2$		TLE4990-E6782
Linearity	$Lin$	99.9	100	100.1	%	<sup>5)</sup>
Temperature coefficient of sensitivity	$\alpha$	200	350	500	ppm/ °C	<sup>6)</sup>
Sensitivity drift over lifetime	$\Delta S_L$	-0.9	-	0.9	%	$T_a = 25\text{ °C}$
Zero field drift over temperature	$\Delta B_0$	-500	-	150	$\mu\text{T}$	valid for $S > 80\text{ mV/mT}$ <sup>7)</sup>
Resolution	$B_n$	20	-	60	$\mu\text{T}_{RMS}$	<sup>8)</sup>

1) @  $V_{DD} = 5\text{ V}$

2) In the lowest programmable sensitivity range a sensitivity less or equal to  $\min(S)$  is guaranteed.  
In the highest programmable sensitivity range a sensitivity of greater or equal to  $\max(S)$  is guaranteed.  
The ratio of  $\max(S) / \min(S) \geq 15$ .

3) @  $25\text{ °C}$

4) Not for the -E6782 version.

5)  $B_{10\%}$  is the magnetic field, at which  $V_{OUT} = 0.1 \times V_{DD}$ .

$B_{90\%}$  is the magnetic field, at which  $V_{OUT} = 0.9 \times V_{DD}$ .

$V_{OUT,id} = [0.1 + 0.8 \times (B - B_{10\%}) / (B_{90\%} - B_{10\%})] \times V_{DD}$ .

$Lin = (V_{OUT} / V_{OUT,id} - 1) \cdot 100\%$  for all  $V_{OUT}$  between  $10\% V_{DD}$  and  $90\% V_{DD}$ .

6) The temperature coefficient of the magnetic sensitivity is the slope of a linear least-square fit through the real curve.

7) For lower sensitivities, the zero voltage drift is dominant (see [Table 4](#)).

8) Equivalent to magnetic input noise at  $25\text{ °C}$ . The equivalent magnetic input noise depends on the selected sensitivity. At highest sensitivity it is typically  $25\ \mu\text{T}_{RMS}$ , at lowest sensitivity it is typically  $50\ \mu\text{T}_{RMS}$  at  $25\text{ °C}$ .

## 6 Signal Processing

### 6.1 Magnetic Field Ranges

*Note: The Range setting is fixed in the -E6782 version.*

The output signal of the Hall cell is amplified in the pre-amplifier.

Eight ranges can be selected by setting the PRE bits.

The output voltage range of 3 ... 97% of  $V_{DD}$  leads to a swing of 4.7 V at  $V_{DD} = 5$  V.

Therefore the product of sensitivity and full scale range is always 4.7 V.

*Note: Sensitivity x Full Scale range = 4.7 V*

**Table 6 Range Setting**

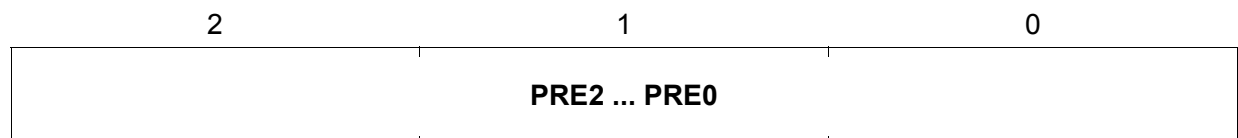
Range	PRE bits			Sensitivity (mV/mT) Typical Values		Magnetic Full Scale Range (mT)	
	PRE2	PRE1	PRE0	min.	max.	min.	max.
0	0	0	0	11.49	16.49	285	409
1	0	0	1	16.17	23.20	203	291
2	0	1	0	22.75	32.65	144	207
3	0	1	1	32.00	45.96	102	147
4	1	0	0	45.04	64.63	72.7	104
5	1	0	1	63.38	90.92	51.7	74.2
6	1	1	0	89.16	127.9	36.8	52.7
7	1	1	1	125.5	180.0	26.1	37.5

In the bipolar mode, the full scale range is composed of a positive and a negative part with the half value each. (e.g.  $\pm 142.4$  mT ...  $\pm 204.4$  mT in range 0).

*Note: The range should be set before the calibration of the gain.*

#### Range register

#### PRE (Preamplifier)



## 6.2 Gain Setting

*Note: The Gain setting is fixed in the -E6782 version.*

The sensitivity is defined by the range (Preamp) and the gain setting. The output of the preamplifier is multiplied with the gain value.

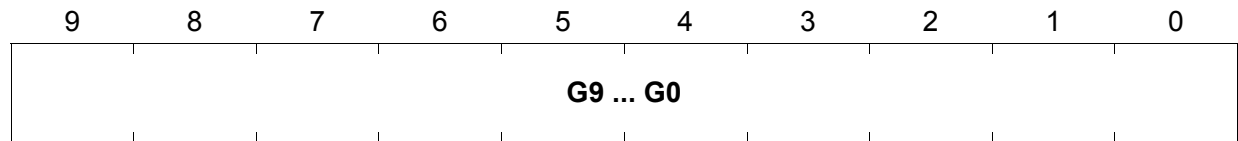
The sensitivity can be set in 1024 steps.

**Table 7 Gain**

Parameter	Symbol	Limit Values		Unit	Notes
		min.	max.		
Register size	-	10		bit	
Gain range	-	1	1.43	-	

### Gain Register

#### Gain



**Table 8 Gain Register Setting**

Gain	G		Remark
	Dec.	Bin. (G9 ... G0)	
1	0	000000000	minimum gain
1.43	1023	111111111	maximum gain

### 6.3 Offset Setting

*Note: The Offset value is fixed in the -E6782 version*

The offset voltage corresponds to an output voltage with zero field at the sensor. It can be set in 1024 steps in two different voltage ranges.

**Table 9 Offset**

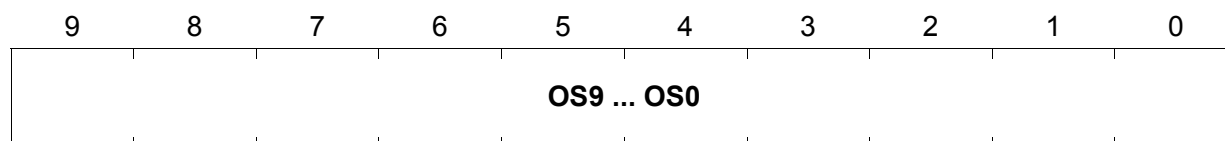
Parameter	Symbol	Limit Values		Unit	Notes
		min.	max.		
Register size	-	10		bit	
Offset range	-	3 40	19 60	% of $V_{DD}$	Bipolar-Bit = 0 <sup>1)</sup> <sup>2)</sup> Bipolar-Bit = 1
Offset quantization steps	$\Delta V_{OS}$	0.97 1.22		mV	Bipolar-Bit = 0 <sup>2)</sup> Bipolar-Bit = 1

<sup>1)</sup> The -E6782 version is programmed to 50%  $V_{DD}$ .

<sup>2)</sup>  $V_{DD} = 5\text{ V}$

### Offset Register

#### Offset



**Table 10 Offset Register Setting**

Offset	OS		BIP	Remark
	Dec.	Bin. (OS9 ... OS0)		
3% of $V_{DD}$	0	0000000000	0	Unipolar
40% of $V_{DD}$	0	0000000000	1	Bipolar
19% of $V_{DD}$	1023	1111111111	0	Unipolar
60% of $V_{DD}$	1023	1111111111	1	Bipolar



## 6.4 Clamping

Note: The Clamping function is not enabled in the -E6782 version

The clamping function is useful to split the output voltage range into operating range and error ranges.

If the magnetic field is outside the selected measurement range, the output voltage  $V_{out}$  is limited to the clamping values.

Therefore an output voltage in the error range indicates a wire breakage (see [Open Circuit \(OBD parameters\)](#), [Table 12](#)) or a short circuit.

The clamping function is enabled, when the clamp bit is set.

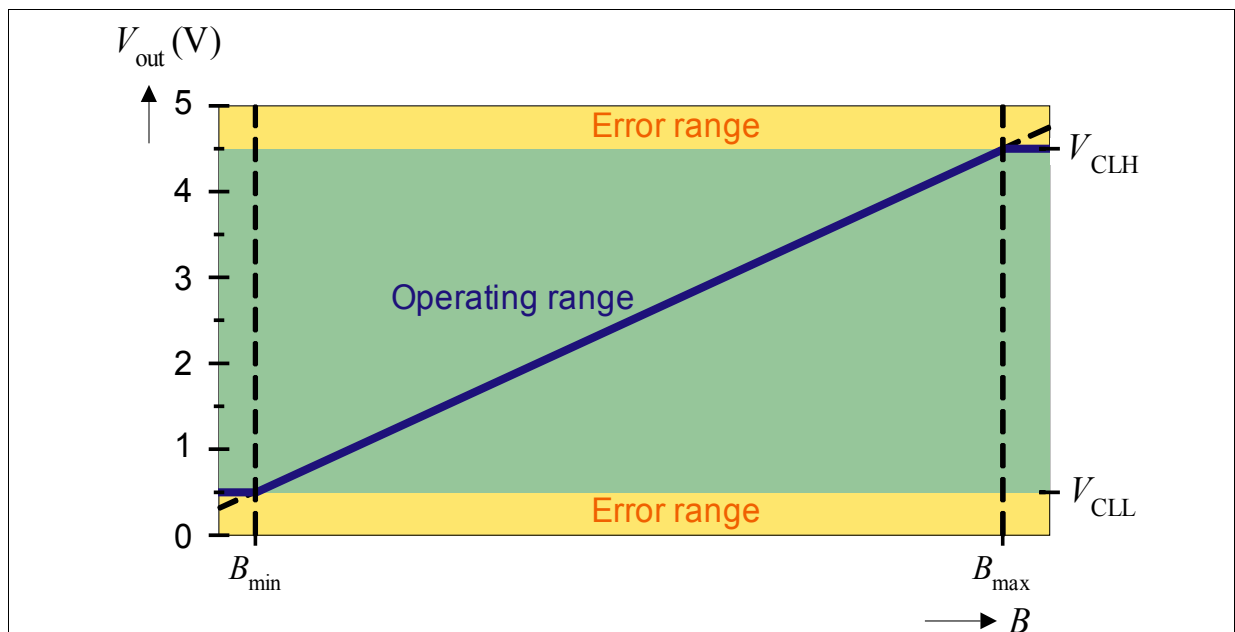
**Table 11 Clamping Ranges**

Parameter	Symbol	Limit Values		Unit	Notes
		min.	max.		
Clamping voltage low	$V_{CL,low}$	8	12	%	of $V_{DD}$ <sup>1)</sup>
Clamping voltage high	$V_{CL,high}$	88	92	%	of $V_{DD}$ <sup>1)</sup>

<sup>1)</sup>  $R_{LOAD} \geq 4.7 \text{ k}\Omega$

The following figure shows how the magnetic field range between  $B_{min}$  and  $B_{max}$  is mapped to voltages between 0.5 V and 4.5 V.

If it is not necessary to signal errors, the clamping should be disabled. In this case the maximum output voltage range between 0.3 V and 4.7 V can be used.



**Figure 5 Clamping**

## 7 Error Detection

Broken supply lines can be detected by the OBD (On Board Diagnostics) and reported to the  $\mu$ Controller.

*Note: The OBD is only useful when the clamping function is enabled.*

In the case of interrupted supply lines, the  $\mu$ Controller may warn the user.

If two sensors are placed in parallel, the output of the remaining working sensor may be still used for an emergency operation.

**Table 12 Open Circuit (OBD parameters)**

Parameter	Symbol	Limit Values		Unit	Notes
		min.	max.		
Output voltage @ Open $V_{DD}$ line	$V_{OUT}$	0	6	% $V_{DD}$	1)
Output voltage @ Open $V_{SS}$ line	$V_{OUT}$	94	100	% $V_{DD}$	1)

<sup>1)</sup> With  $R_L \geq 7 \text{ k}\Omega$

## 8 Calibration and Fusing

Usually the sensor is calibrated 'End Of Line', when the complete magnetic system is assembled. This compensates all magnetic and mechanical tolerances.

*Note: The -E6782 version is already programmed completely. The contents of the calibration OTP memory may not be changed furthermore.*

During the calibration the internal settings are stored in a RAM. When the right values are found, the information has to be stored in an one-time-programmable memory (OTP).

This OTP memory consists of cavity fuses.

After fusing all bits, setting the MEMLOCK bit closes the memory. This prevents from unwanted memory changes after the calibration

### Data Transfer Protocol

A separate programming specification may be requested.

### Programming of Sensors with Common Supply Lines

In many automotive applications two sensors are used to measure the same parameter. This redundancy allows to continue the operation in an emergency mode. If both sensors use the same power supply lines, they have to be programmed together.

### Sensor Interface Tool

For the calibration of the sensor, a special hardware interface to a PC is required.

## 9 Application Circuit

Figure 6 shows the connection of multiple sensors to a  $\mu$ -Controller.

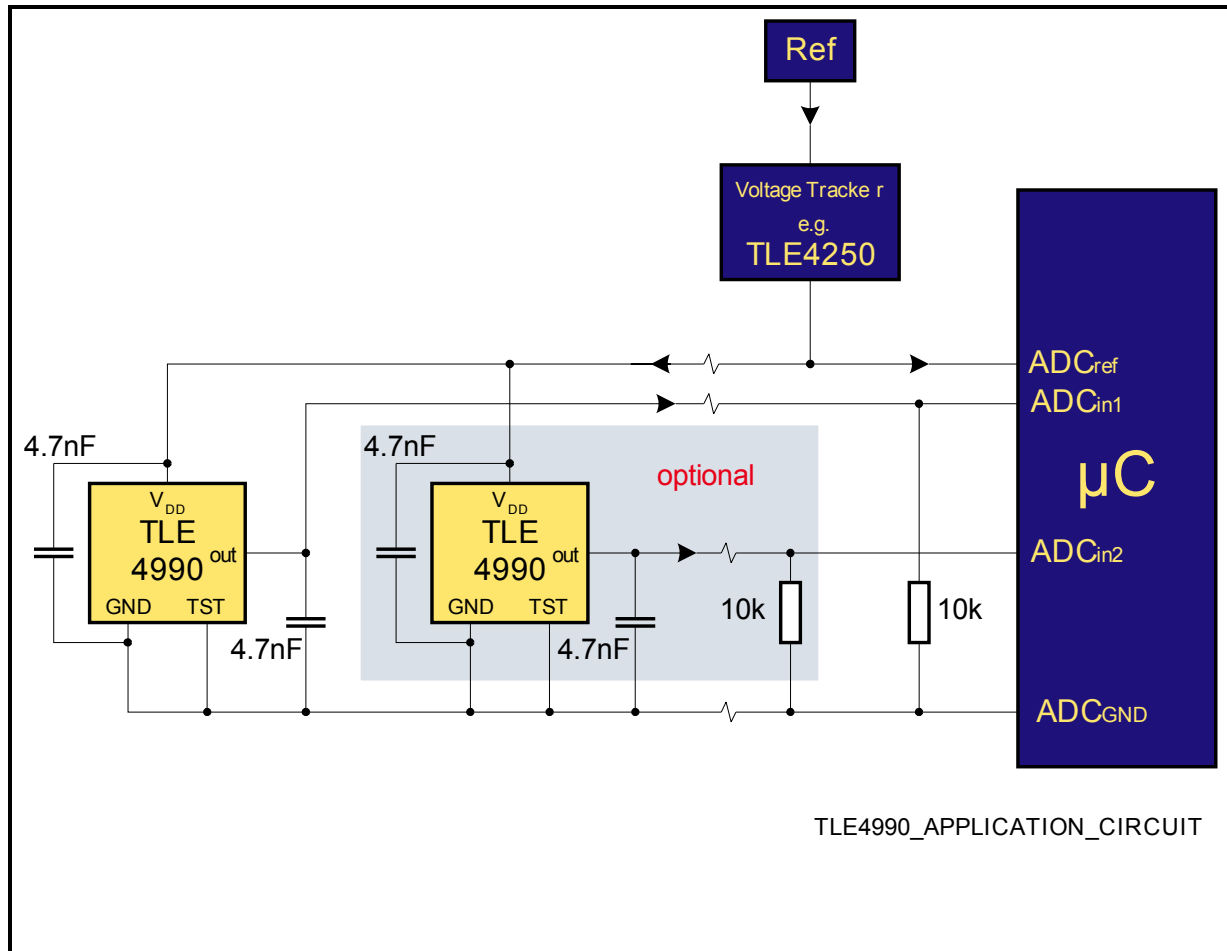


Figure 6 Application Circuit

## 10 Package Outlines

P-SSO-4-1

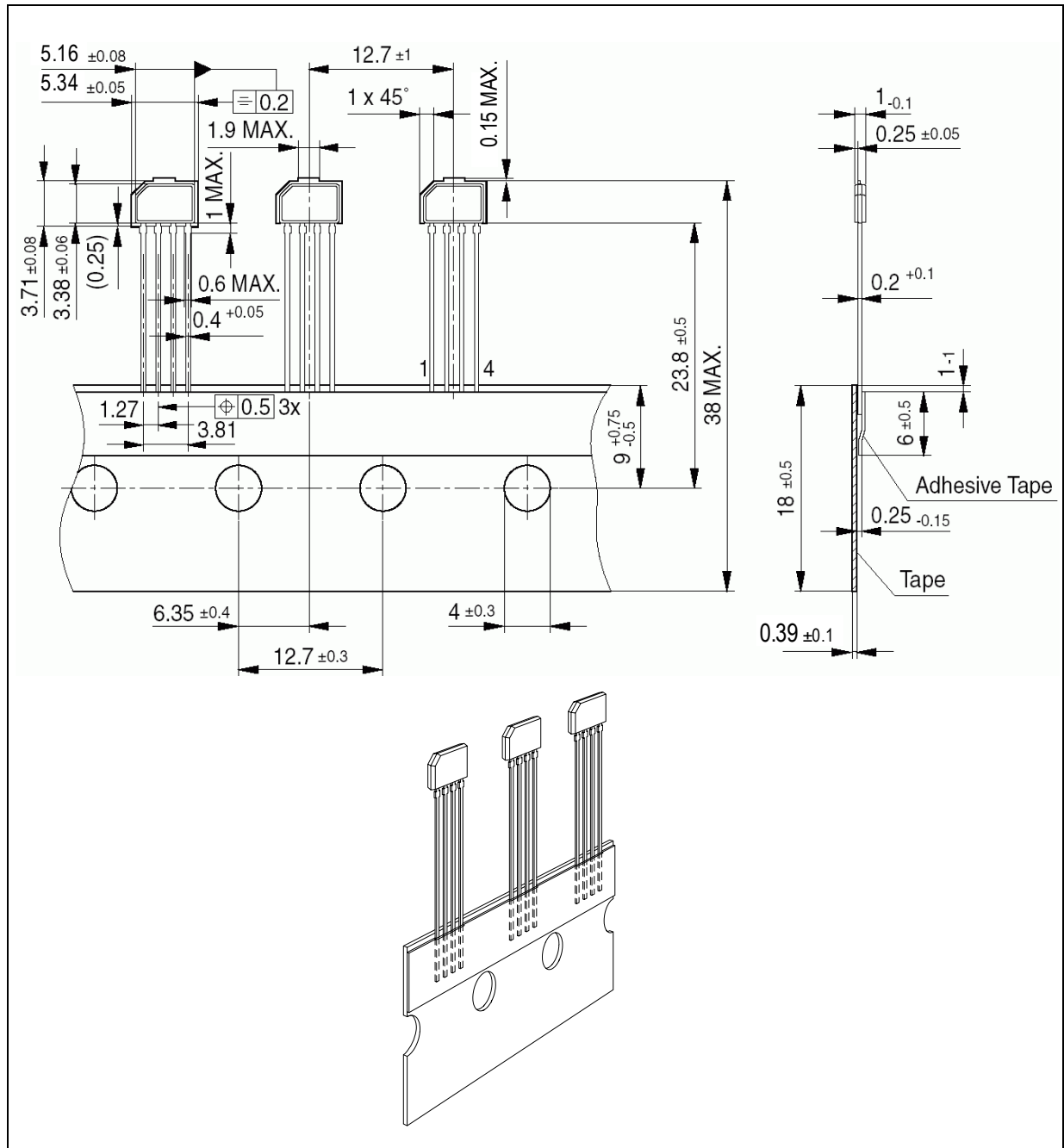


Figure 7 Package Outline





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